NSN 5962-01-287-8528

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View Online at https://aerobasegroup.com/nsn/5962-01-287-8528 **Body Length:** Between 1.435 inches and 1.485 inches **Body Width:** Between 0.515 inches and 0.599 inches **Body Height:** Between 0.140 inches and 0.180 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **End Application:** 7010-01-211-9822 **Features Provided:** Hermetically sealed and programmable and ultraviolet erasable and w/enable and bidirectional and electrostatic sensitive **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic

Input Circuit Pattern:

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Terminal Surface Treatment:

Solder

25 input

Voltage Rating And Type Per Characteristic:

-0.6 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

250.00 nanoseconds propagation delay time, low to high level output and 250.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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